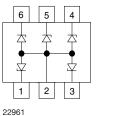


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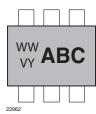
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Five-Line ESD Protection Diode Array in SOT-363





MARKING (example only)



Bar = cathode marking

X = date code

Y = type code (see table below)

DESIGN SUPPORT TOOLS AVAILABLE



FEATURES

- Compact SOT-363 package
- 5-line unidirectional ESD-protection
- Working range 5V to 26 V
- ESD immunity acc. IEC 61000-4-2 ±20kV to ± 30 kV contact discharge ±20kV to ± 30 kV air discharge
- AEC-Q101 qualified available
- Lead plating: Sn (e3)
 - soldering can be checked by standard vision inspection
 - (AOI = automated optical inspection)
- · Material categorization: for definitions of compliance







HALOGEN FREE

GREEN (5-2008)

please see www.vishav.com/doc?99912

ORDERING INFORMATION									
		ENVIRON	MENTAL AND QUALITY	CODE					
PART NUMBER (EXAMPLE)	I FAD (Ph)-FRE		TIN PLATED	3K PER 7" REEL (8 mm TAPE)	ORDERING CODE (EXAMPLE)				
		GREEN		MOQ = 15K/BOX					
VESD05A5-06G	-	G	3	-08	VESD05A5-06G-G3-08				
VESD05A5-06G	Н	G	3	-08	VESD05A5-06GHG3-08				

PACKAGE DATA										
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS				
VESD05A5-06G		D05								
VESD12A5-06G	SOT-363	D12	7 00 ma	III 04 V 0	MSL level 1	Peak temperature				
VESD16A5-06G	501-303	D16	7.22 mg	UL 94 V-0	(according J-STD-020)	max. 260°C				
VESD26A5-06G		D26								





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ABSOLUTE MAXIMUM RATINGS VESD05A5-06G									
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT					
Peak pulse current	Acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	8.7	Α					
Peak pulse power	Acc. IEC 61000-4-5, 8/20 µs/single shot	P _{PP}	100	W					
FOD :	Contact discharge acc. IEC 61000-4-2; 10 pulses		30	kV					
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	30	kV					
Operating temperature	Junction temperature	T _J	-55 to +150	°C					
Storage temperature		T _{stg}	-55 to +150	°C					

ABSOLUTE MAXIMUM RATINGS VESD12A5-06G									
PARAMETER	TEST CONDITIONS	TEST CONDITIONS SYMBOL VALUE							
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I _{PPM}	4.4	Α					
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μs/single shot	P _{PP}	100	W					
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	30	kV					
ESD IIIIIIIIIIII	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	30	kV					
Operating temperature	Junction temperature	TJ	-55 to +150	°C					
Storage temperature		T _{stg}	-55 to +150	°C					

ABSOLUTE MAXIMUM RATINGS VESD16A5-06G									
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT					
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I _{PPM}	3.6	Α					
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μs/single shot	P _{PP}	100	W					
ECD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	30	kV					
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	3.6	kV					
Operating temperature	Junction temperature	TJ	-55 to +150	°C					
Storage temperature		T _{stg}	-55 to +150	°C					

ABSOLUTE MAXIMUM RATINGS VESD26A5-06G									
PARAMETER	TEST CONDITIONS	UNIT							
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I _{PPM}	2.1	Α					
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μs/single shot	P _{PP}	100	W					
ECD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	W	20	kV					
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	20	kV					
Operating temperature	Junction temperature	T_J	-55 to +150	°C					
Storage temperature		T _{stg}	-55 to +150	°C					



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ELECTRICAL CHARACTERISTICS VESD05A5-06G (T _{amb} = 25 °C, unless otherwise specified)										
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT				
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines				
Reverse stand off voltage	Max. reverse working voltage	V_{RWM}	-	-	5	V				
Reverse voltage	at I _R = 1 μA	V_R	5	-	-	V				
Reverse current	at V _R = 5 V	I _R	-	0.01	0.1	μA				
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	6.85	7.26	7.65	V				
Reverse clamping voltage	at $I_{PP} = I_{PPM} = 8.7 \text{ A}$, $t_p = 8/20 \mu\text{s}$	V _C	-	10.3	11.5	V				
Forward clamping voltage	at $I_{PP} = 1 \text{ A}$, $t_p = 300 \mu\text{s}$	V_{F}	0.9	1.1	1.2	V				
Torward clamping voltage	at $I_{PP} = I_{PPM} = 8.7 \text{ A}, t_p = 8/20 \mu s$	V_{F}	-	2.2	2.74	V				
Dynamic resistance	$t_p = 100 \text{ ns (TLP; pin 2-1)}$	r _{dyn}	-	0.2	-	Ω				
Capacitance	at $V_R = 0 V$; $f = 1 MHz$	C_D	53	67	81	pF				

ELECTRICAL CHARACTERISTICS VESD12A5-06G (T _{amb} = 25 °C, unless otherwise specified)										
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT				
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines				
Reverse stand off voltage	Max. reverse working voltage	V_{RWM}	-	-	12	V				
Reverse voltage	at I _R = 0.1 μA	V_R	12	-	-	V				
Reverse current	at V _R = 12 V	I _R	-	0.01	0.1	μΑ				
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	13.9	14.7	15.5	V				
Reverse clamping voltage	at $I_{PP} = I_{PPM} = 4.4 \text{ A}$, $t_p = 8/20 \mu\text{s}$	V _C	-	20.5	22.7	V				
Famus rd alamaning valtage	at $I_{PP} = 1 \text{ A}$, $t_p = 300 \mu\text{s}$	V_{F}	0.9	1.1	1.2	V				
Forward clamping voltage	at $I_{PP} = I_{PPM} = 4.4 \text{ A}, t_p = 8/20 \mu\text{s}$	V _F	-	1.6	1.88	V				
Dynamic resistance	t _p = 100 ns (TLP); pin 2-1	r _{dyn}	-	0.4	-	Ω				
Capacitance	at V _R = 0 V; f = 1 MHz	C _D	26	33	40	pF				

ELECTRICAL CHARACTERISTICS VESD16A5-06G (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines			
Reverse stand off voltage	Max. reverse working voltage	V_{RWM}	-	-	16	V			
Reverse voltage	at I _R = 0.1 μA	V_R	16	-	-	V			
Reverse current	at V _R = 16 V	I _R	-	0.01	0.1	μΑ			
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	17	17.9	18.8	V			
Reverse clamping voltage	at $I_{PP} = I_{PPM} = 3.6 \text{ A}, t_p = 8/20 \mu\text{s}$	V _C	-	25.3	28	V			
Commend alamanian maltana	at I _{PP} = 1 A, t _p = 300 μs	V _F	0.9	1.1	1.2	V			
Forward clamping voltage	at I _{PP} = I _{PPM} = 3.6 A, t _p = 8/20 μs	V_{F}	-	1.5	1.72	V			
Dynamic resistance	t _p = 100 ns (TLP); pin 2-1	r _{dyn}	-	0.53	-	Ω			
Capacitance	at V _R = 0 V; f = 1 MHz	C_D	21	27	33	pF			



VESD05A5-06G to VESD26A5-06G

ELECTRICAL CHARACTERISTICS VESD26A5-06G (T _{amb} = 25 °C, unless otherwise specified)										
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT				
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines				
Reverse stand off voltage	Max. reverse working voltage	V_{RWM}	-	-	26	V				
Reverse voltage	at I _R = 0.1 μA	V_R	26	-	-	V				
Reverse current	at V _R = 26 V	I _R	-	< 0.01	0.1	μA				
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	27.6	29.1	30.6	V				
Reverse clamping voltage	at I _{PP} = I _{PPM} = 2.1 A, t _p = 8/20 μs	V _C	-	43	48	V				
Famusard alamaning valtage	at $I_{PP} = 1 \text{ A}$, $t_p = 300 \mu\text{s}$	V_{F}	0.9	1.1	1.2	V				
Forward clamping voltage	at I _{PP} = I _{PPM} = 2.1 A, t _p = 8/20 μs	V_{F}	-	1.3	1.42	V				
Dynamic resistance	t _p = 100 ns (TLP); pin 2-1	r _{dyn}	-	1.9	-	Ω				
Capacitance	at V _R = 0 V; f = 1 MHz	C _D	14	17.5	21	pF				

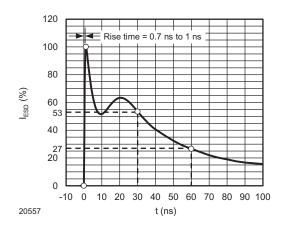


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω / 150 pF)

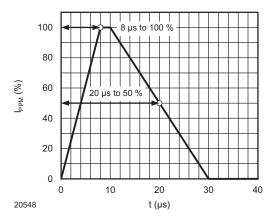


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

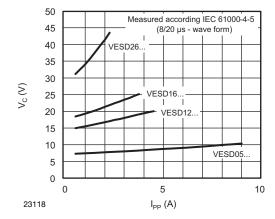


Fig. 3 - Typical Peak Clamping Voltage vs. Peak Pulse Current

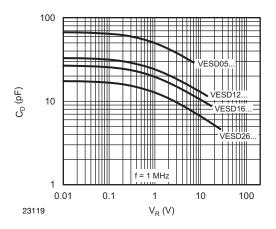


Fig. 4 - Typical Capacitance vs. Reverse Voltage

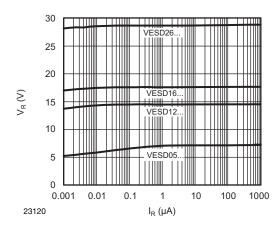


Fig. 5 - Typical Reverse Voltage vs. Reverse Current

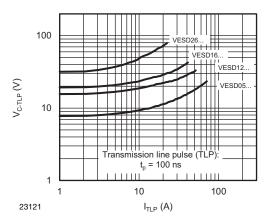
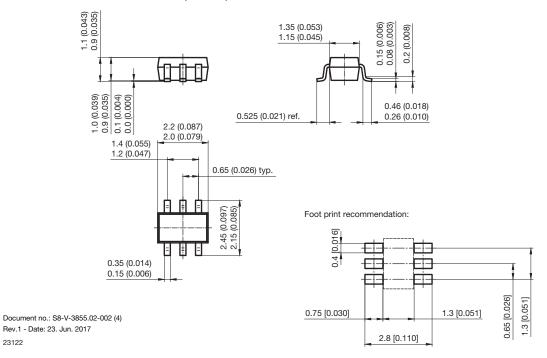


Fig. 6 - Typical Clamping Voltage vs. Peak Pulse Current

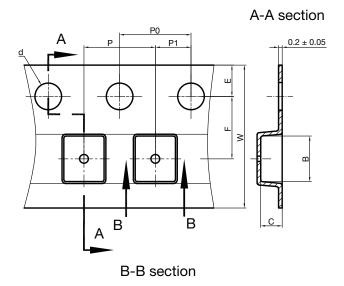
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PACKAGE DIMENSIONS in millimeters (Inches): SOT-363



CARRIER TAPE SOT-363

23122





Cummulative tolerances of 10 sprocket holes is \pm 0.2 mm

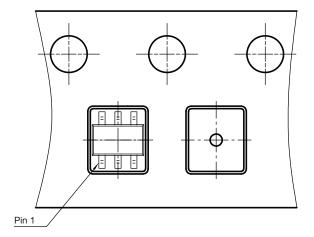
Dimensions in millimeters										
Packaging type	Α	В	С	d	Е	F	P0	Р	P1	W
SOT-363	2.25	2.55	1.20	Ø 1.5	1.75	3.50	4.00	4.00	2.00	8.00
(Tolerance)	± 0.1	± 0.1	± 0.1	+0.1/-0	± 0.1	± 0.1	± 0.05	± 0.1	± 0.05	+0.3/-0.1

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ORIENTATION IN CARRIER TAPE SOT-363



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